



Attorney Docket, SEL 123

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of)
)
Akiharu MIYANAGA et al.)
)
Serial No.: 09/241,695)
)
Filed: February 2, 1999)
)
For: Semiconductor Device And)
Process For Producing The Same)
)
Art Unit: 2811)
)
Examiner: S. Hu)

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Date 10/24/01

Commissioner for Patents
Washington, D.C. 20231

AMENDMENT AFTER FINAL

Please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claim 49. ✓

Please amend claims 1, 27-29, 34, 42 and 48 as follows:

1. (Amended) A semiconductor device comprising a plurality of MOSFETs formed in a single crystal semiconductor substrate,
- each of the plurality of MOSFETs comprising:
- a source region and a drain region each including a first impurity;
- a channel forming region being formed between the source region and the drain region; and